

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	540	ink same refill\$3 same tube\$3	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:50
2	BRS	L2	244	cartridge\$3 and carriage\$3 and 1	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:51
3	BRS	L3	0	gas and microcapsule\$3 and 2	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:52
4	BRS	L4	6488	gas and microcapsule\$3	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:11
5	BRS	L5	122	(pressure same regulator\$3) and 4	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:53
6	BRS	L8	0	6 and 7	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:53
7	BRS	L6	5	semiconductor\$3 and 5	USPAT; US-PGP UB; EPO; JPO	2004/09/25 23:54
8	BRS	L7	26	semiconductor\$3 and 2	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:07

	Type	L #	Hits	Search Text	DBs	Time Stamp
9	BRS	L9	2662	translat\$5 same cartridge\$3	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:07
10	BRS	L10	32	2 and 9	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:08
11	BRS	L11	56771	347/\$.ccls.	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:11
12	BRS	L12	90	4 and 11	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:12
13	BRS	L13	88	ink same eject\$3 same nanogram\$3	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:13
14	BRS	L15	0	12 and 14	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:13
15	BRS	L14	43	dlc and 13	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:31
16	BRS	L16	92831	silicon same wafer\$3	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:34

	Type	L #	Hits	Search Text	DBs	Time Stamp
17	BRS	L17	1770	11 and 16	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:34
18	BRS	L18	28	cmos and fet and 17	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:35
19	BRS	L19	8498	cmos same gate same oxide	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:35
20	BRS	L20	2	18 and 19	USPAT; US-PGP UB; EPO; JPO	2004/09/26 00:35